NSN 5961-00-887-5830

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View Online at https://aerobasegroup.com/nsn/5961-00-887-5830 **Inclosure Material:** Metal **Overall Length:** 0.772 inches **Terminal Length:** 1.490 inches **Overall Diameter:** 0.390 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current and 250.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 18876-9176456 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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